

### L6234 THREE PHASE MOTOR DRIVER

by Domenico Arrigo

#### INTRODUCTION

The L6234 is a DMOSs triple half-bridge driver with input supply voltage up 52V and output current of 5A. It can be used in a very wide range of applications.

It has been realized in Multipower BCD60II technology which allows the combination of isolated DMOS transistors with CMOS and Bipolar circuits on the same chip. It is available in Power DIP 20 (16+2+2) and in Power SO 20 packages.

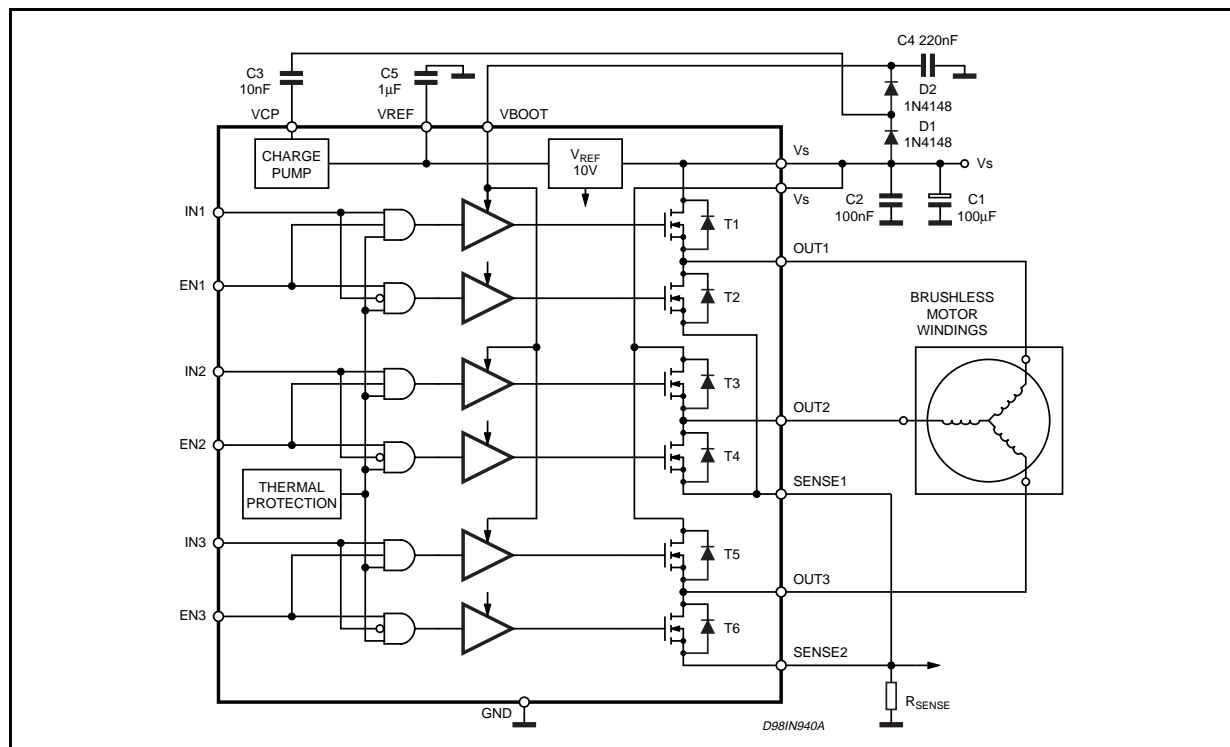
All the inputs are TTL/CMOS compatible and each half bridge can be driven by its own dedicated input and enable.

The DMOS structure has an intrinsic free wheeling body diode so the use of external diodes, which are necessary in the bipolar configuration, can be avoided. The DMOS structure allows a very low quiescent current of 6.5 mA typ. at  $V_s=42V$ , irrespective of the load.

#### DEVICE DESCRIPTION

The device is composed of three channels. Each channel is composed of a half bridge with two power DMOS switches (typ.  $R_{ds(on)}$  of 300mW @ 25°C) and intrinsic free wheeling diodes. Each channel includes two TTL/CMOS and uP compatible comparators, and a logic block to interface the inputs with the drivers. The device includes an internal bandgap reference of 1.22V, a 10V voltage reference to supply the internal circuitry of the device, a central charge pump to drive the upper DMOS switch, thermal shut-down protection and an internal hysteretic function which turns off the device when the junction temperature exceeds approximately 160 °C. Hysteresis is about 20 °C.

**Figure 1. L6234 Block Diagram**



## PIN DESCRIPTION.

### Vs ( INPUT SUPPLY VOLTAGE PINS).

These are the two input supply voltage pins. The unregulated input DC voltage can range from 7V to 52V.

With inductive loads the recommended operating maximum supply voltage is 42V to prevent overvoltage applied to the DMOSfets. In fact considering a full bridge configuration (see fig. 2), when the bridge is switched off (ENABLE CHOPPING) the current recirculation produces a negative voltage to the source of the lower DMOS switches (point A). In this condition the drain-source voltage of T<sub>1</sub> and T<sub>4</sub> is  $V_S + V_F + V_{sense}$ . Dynamically  $V_F$  can be some Volts depending on the current slope,  $di/dt$ , and also  $V_{sense}$ , depending on the parasitic inductance and current slope can be some Volts. So the drain-source voltage of T<sub>1</sub> and T<sub>4</sub> DMOS switches can reach more than 10V over the  $V_S$  voltage. The input capacitors C1 and C2 are chosen in order to reduce overvoltage due to current decay and to parasitic inductance. For this reason C2 has to be placed as closed as possible to  $V_S$  and GND pins.

The device can sustain a 4A DC input current for each of the two  $V_S$  pins, in accordance with the power dissipation.

**OUT1, OUT2, OUT3 (OUTPUTS).** These are the output pins that correspond to the mid point of each half bridge. They are designed to sustain a DC current of 4A.

### SENSE1, SENSE2.

SENSE1 is the common source of the lower DMOS of the half bridge 1 and 2.

SENSE2 is the source of the lower DMOS of the half bridge 3.

Each of these pins can handle a current of 5A.

A resistance,  $R_{sense}$ , connected to these pins provides feedback for motor current control.

Care must be taken with the negative voltage applied to these pins : negative DC voltage lower than -1V could damage the device. For duration lower than 300ns the device can sustain pulsed negative voltage up to -4V.

For example, if enable chopping current control method is used, negative voltage pulses appear to these pins, due to the current recirculation through the sensing resistor.

### Vref ( Voltage Reference).

This is the internal 10V voltage reference pin to bias the logic and the low voltage circuitry of the device. A 1 $\mu$ F electrolytic capacitor connected from this pin to GND ensures the stability of the DMOS drive circuit. This pin can be externally loaded up to 5mA . Figure 3 and 4 show the typical behavior of the Vref pin.

### Vcp ( CHARGE PUMP ).

This is the internal oscillator output pin for the charge pump. The oscillator supplied by the 10V Voltage Reference switches from GND to 10V with a typical frequency of

Figure 2.

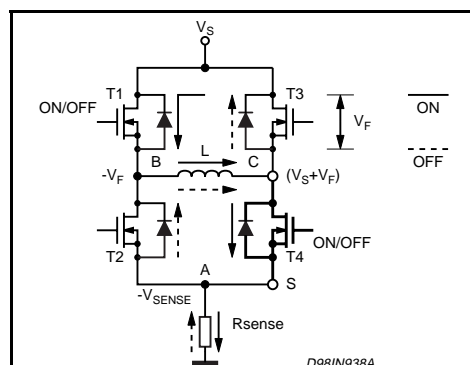


Figure 3. Reference Voltage vs. Junction Temperature.

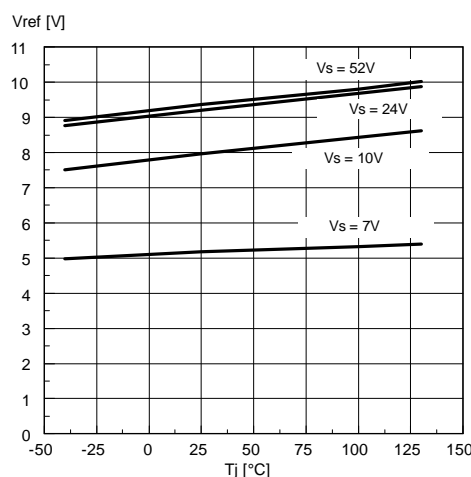
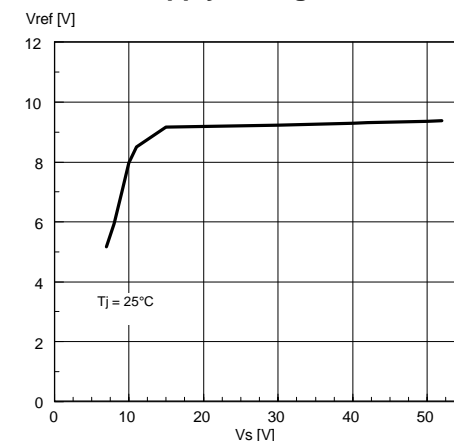


Figure 4. Reference Voltage vs. Supply Voltage.

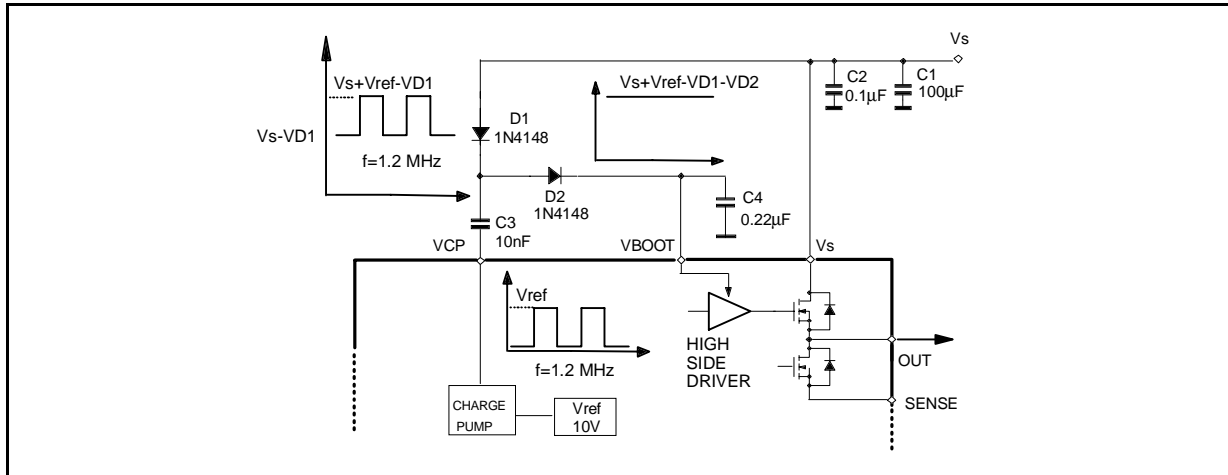


1.2MHz (see fig 4). When the oscillator output is at ground, C3 is charged by  $V_s$  through D1. When it rises to 10V, D1 is reverse biased and the charge flows from C3 to C4 through D2, so the Vboot pin after a few cycles reaches the maximum voltage of  $V_s + 10V - V_{D1} - V_{D2}$ .

### Vboot ( BOOTSTRAP).

This is the input bootstrap pin which gives the overvoltage necessary to drive all the upper DMOS of the three half bridges (see fig 5).

Figure 5. Charge Pump Circuit.



### LOGIC INPUTS PINS.

#### EN1, EN2, EN3 (ENABLES).

These pins are TTL/CMOS and  $\mu P$  compatible. Each half bridge can be enabled by its own dedicated pin with a logic HIGH. The logic LOW on these pins switches off the related half bridge (see Fig. 6). The maximum switching frequency is 50kHz.

Figure 6. Control logic for each half bridge.

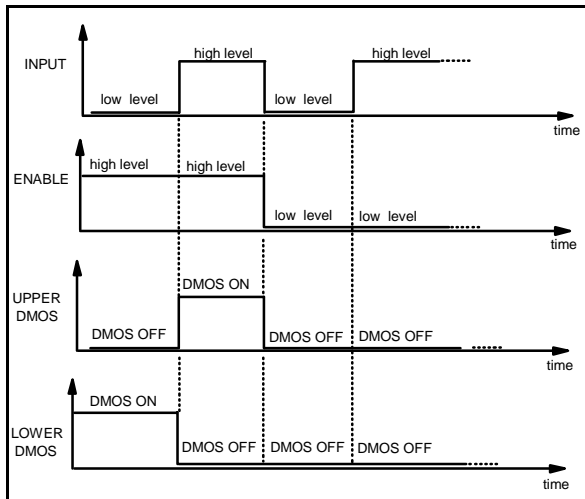
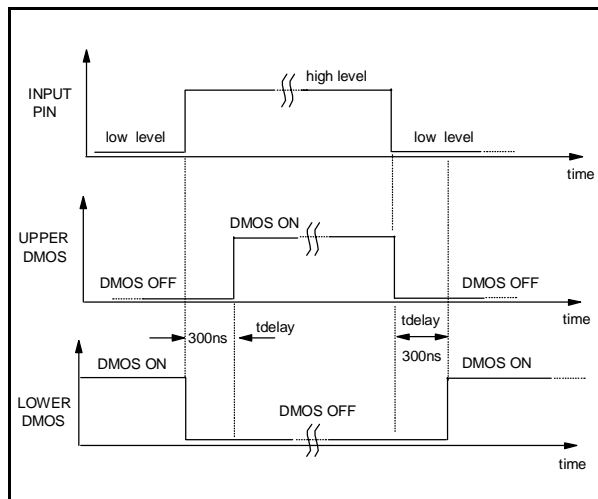


Figure 7. Cross Conduction Protection.



#### IN1, IN2, IN3 (INPUTS).

These pins are TTL/CMOS and  $\mu P$  compatible. They allow switching on the upper DMOS ( INPUT at high logic level) or the lower Dmos (INPUT at low logic level) in each half bridge (see Fig. 6).

## AN1088 APPLICATION NOTE

Cross conduction protection (see Fig. 7) avoids simultaneously turning on both the upper and lower DMOS of each half bridge. There is a fixed delay time of 300ns between the turn on and the turn off of the two DMOS switches in each half bridge. The switching operating frequency is up to 50kHz. High commutation frequency permits the reduction of ripple of the output current but increases the device's power dissipation, however low commutation frequency causes high ripple of the output current. The switching frequency should be higher than 16kHz to avoid acoustic noises.

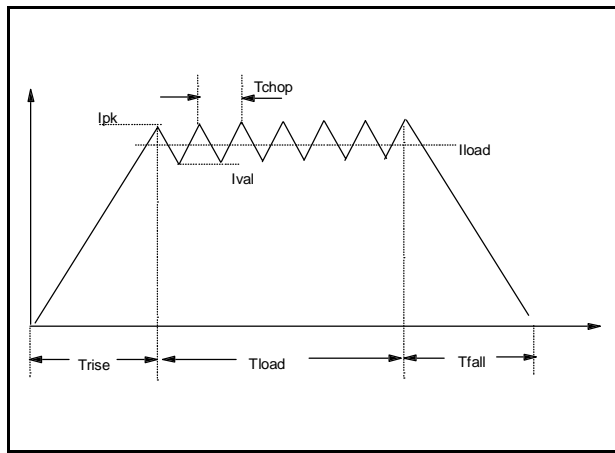
The sink current at the INPUTS and ENABLES pins is approximately 30μA if the voltage to these pins is at least 1V less than the Vref voltage (see Fig. 3 and Fig. 4). To avoid overload of the logic INPUTS and ENABLES, voltage should be applied to Vs prior to the logic signal inputs.

### POWER DISSIPATION

An evaluation of the power dissipation of the IC driving a three phase motor in a chopping current control application follows.

With a simplified approach it can be distinguished three periods (see Fig. 8) :

**Figure 8.**



#### Rise Time, Tr, period.

This is the rise time period, Tr, in which the current switches from one winding to another. In this time a DMOS is switched on and the current increases up to the peak value Ipk with the law  $i(t) = (I_{pk}/T_r) \cdot t$ . The energy lost for the rise time in the period T is :

$$E_{rise} = \int_0^{T_r} R_{dson} \cdot i^2(t) dt = R_{dson} \cdot I_{pk}^2 \cdot \frac{T_r}{3}$$

#### Fall Time, Tf, period.

When the current switches from one winding to another, there is a fall time in which the current that flows in the intrinsic diode of the DMOS decreases from Ipk to zero. If VD is the voltage fall of the diode, the energy lost is :

$$E_{fall} = \int_0^{t_f} V_D(t) \cdot i(t) dt$$

#### Tload

During this time the current that flows in the winding is limited by the chopping current control. The energy dissipated due to the ON resistance of the DMOS is :

$$E_{load} = R_{dson} \cdot (I_{rms})^2 \cdot T_{load}$$

In the formula, Irms is the RMS load current, given by :

$$I_{rms} = \sqrt{(I_{load})^2 + \left( \frac{I_{pk} - I_{val}}{\sqrt{3}} \right)^2}$$

and Iload is the average load current.

When the switch is ON, the energy dissipated due to the commutation of the chopping current control in the DMOS can be assumed to be:

$$E_{on} = V_s \cdot I_{val} \cdot \frac{t_{com}}{2}$$

where tcom is the commutation time of the DMOS switch.

When the switch is OFF :

$$E_{\text{off}} = V_s \cdot I_{\text{pk}} \cdot \frac{t_{\text{com}}}{2}$$

The energy lost by commutation in a chopping period, given by  $E_{\text{on}} + E_{\text{off}}$ , is :

$$E_{\text{com}} = V_s \cdot I_{\text{load}} \cdot t_{\text{com}}$$

The energy lost by commutation during the  $T_{\text{load}}$  time is given by :

$$E_{\text{com}} = V_s \cdot I_{\text{load}} \cdot t_{\text{com}} \cdot T_{\text{load}} \cdot f_{\text{chop}}$$

### Quiescent Power Dissipation, $P_q$ .

The power dissipation due to the quiescent current is  $P_q = V_s \cdot I_q$ , in which  $I_q$  is the quiescent current at the chopping frequency,  $f_{\text{chop}} = 1/T_{\text{chop}}$ .

### Total Power Dissipation.

Let's evaluate the power dissipation of the device driving a three phase brushless motor in chopping current control. In the driving sequence only one upper DMOS and a lower one are on at the same time (see fig. 9 and 10). The total power dissipation is given by :

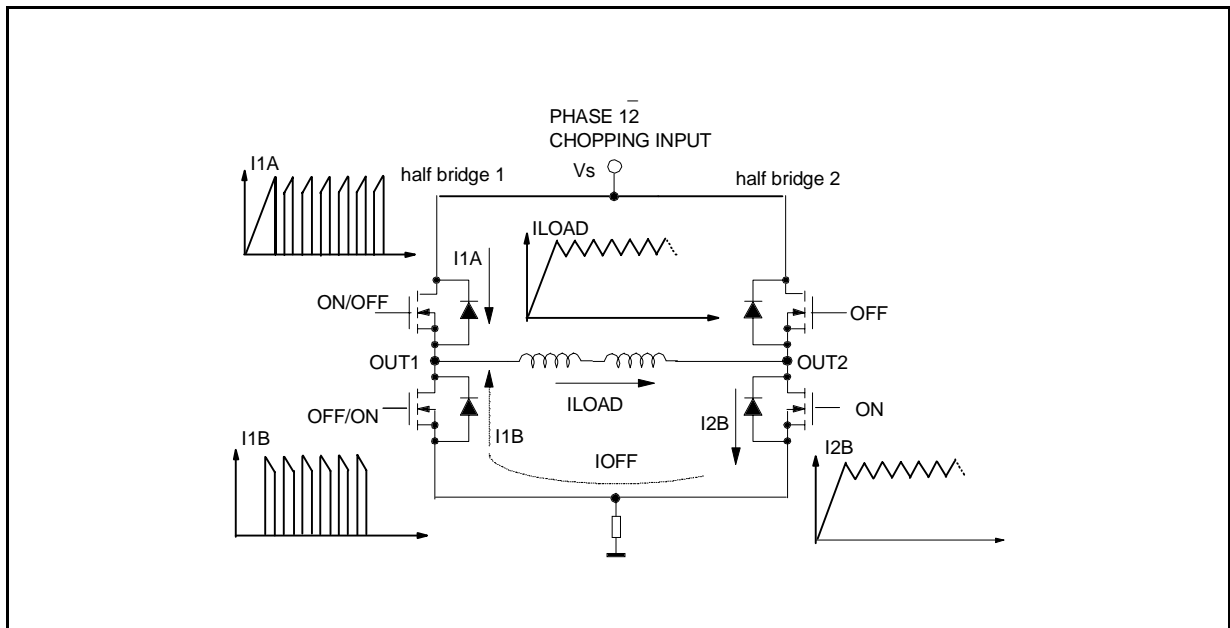
$$P_{\text{tot}} = \frac{2 \cdot (E_{\text{rise}} + E_{\text{fall}} + E_{\text{load}} + E_{\text{com}})}{T} + P_q$$

Figure 11 shows the total power dissipation,  $P_d$ , of the L6234 driving a three phase brushless motor in input chopping current control at different chopping frequency.

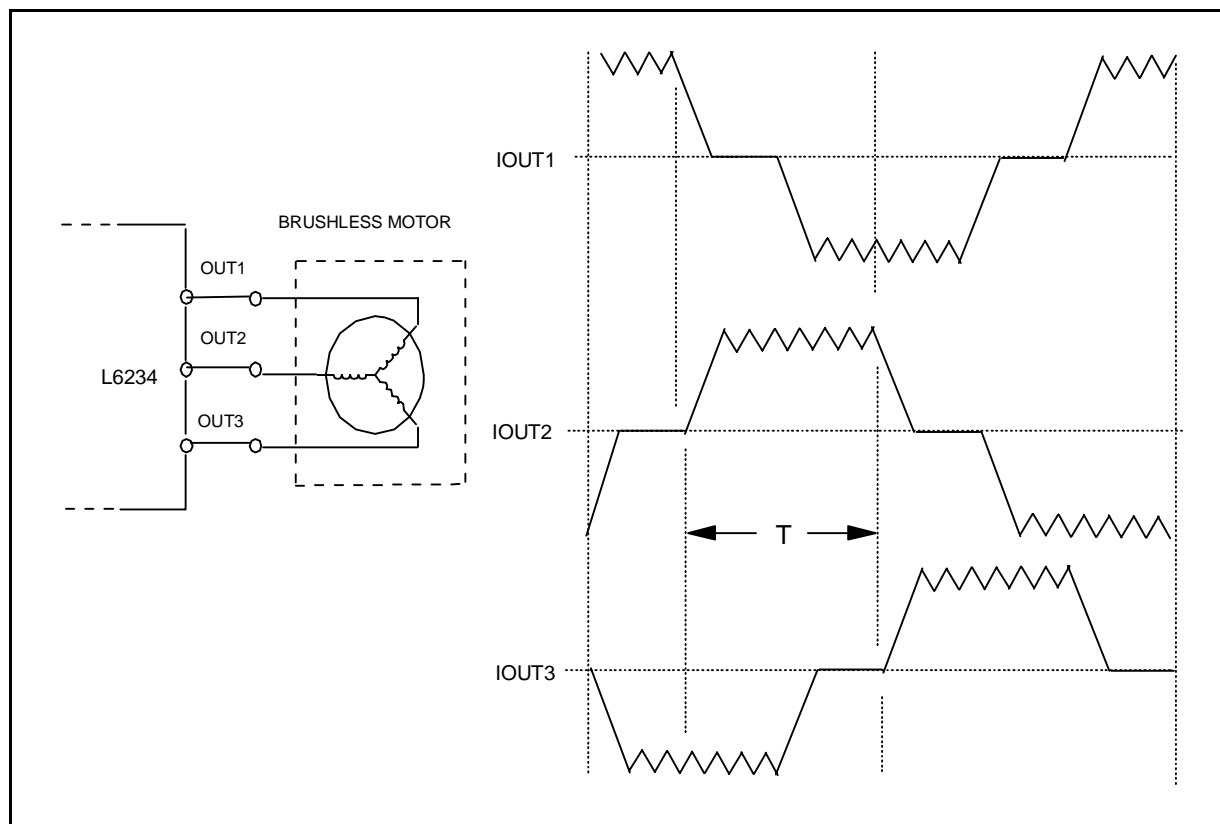
### EVALUATION BOARD.

The L6234 Power SO20 board has been realized to evaluate the device driving, in closed loop control, a three phase brushless motor with open collector Hall effect sensors.

**Figure 9. Input chopping current circulation.**



**Figure 10. Three Phase Brushless motor control sequence.**



The device soldered on the copper heat dissipating area on the board, without any additional heat sink, can sustain a DC load current of 2.3 A at  $T_{amb}$  of approximately 40 °C.

The board provides a closed loop speed and torque control, with a constant  $t_{OFF}$  chopping current control method. It allows the user to change the direction and brake the motor.

## Constant $t_{OFF}$ Chopping Current Control.

When the current through the motor exceeds the threshold, fixed by the ratio between the control voltage  $V_{control}$  and the sensing resistor,  $R_{sense}$ , an error signal is generated, the output of the LM393 comparator switches to ground. This state is maintained by the monostable (M74HC123) for a constant delay time ( $t_{OFF}$ ) generating a PWM signal that achieves the chopping current control. The PWM signal is used for chopping the INPUT pattern. During the toff in chopping current control, the current flows in the low side loop ( see fig. 9 ) and does not flow through the sensing resistor.

The  $t_{OFF}$  value can be set by the R9 and C11 to values shown in the table 1.

A suitable value of toff for the majority of applications is 30 $\mu$ s. The larger the  $t_{OFF}$ , the higher is the current ripple. If the  $t_{OFF}$  is too large the ripple current becomes excessive. On the other hand if the  $t_{OFF}$  is too small the winding current cannot decrease under the threshold and current regulation is not guaranteed.

**Figure 11. L6234 Power Dissipation in Three Phase Brushless Motor Control.**

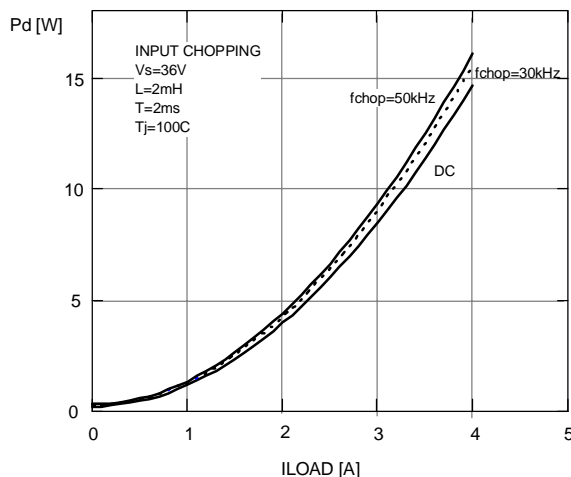
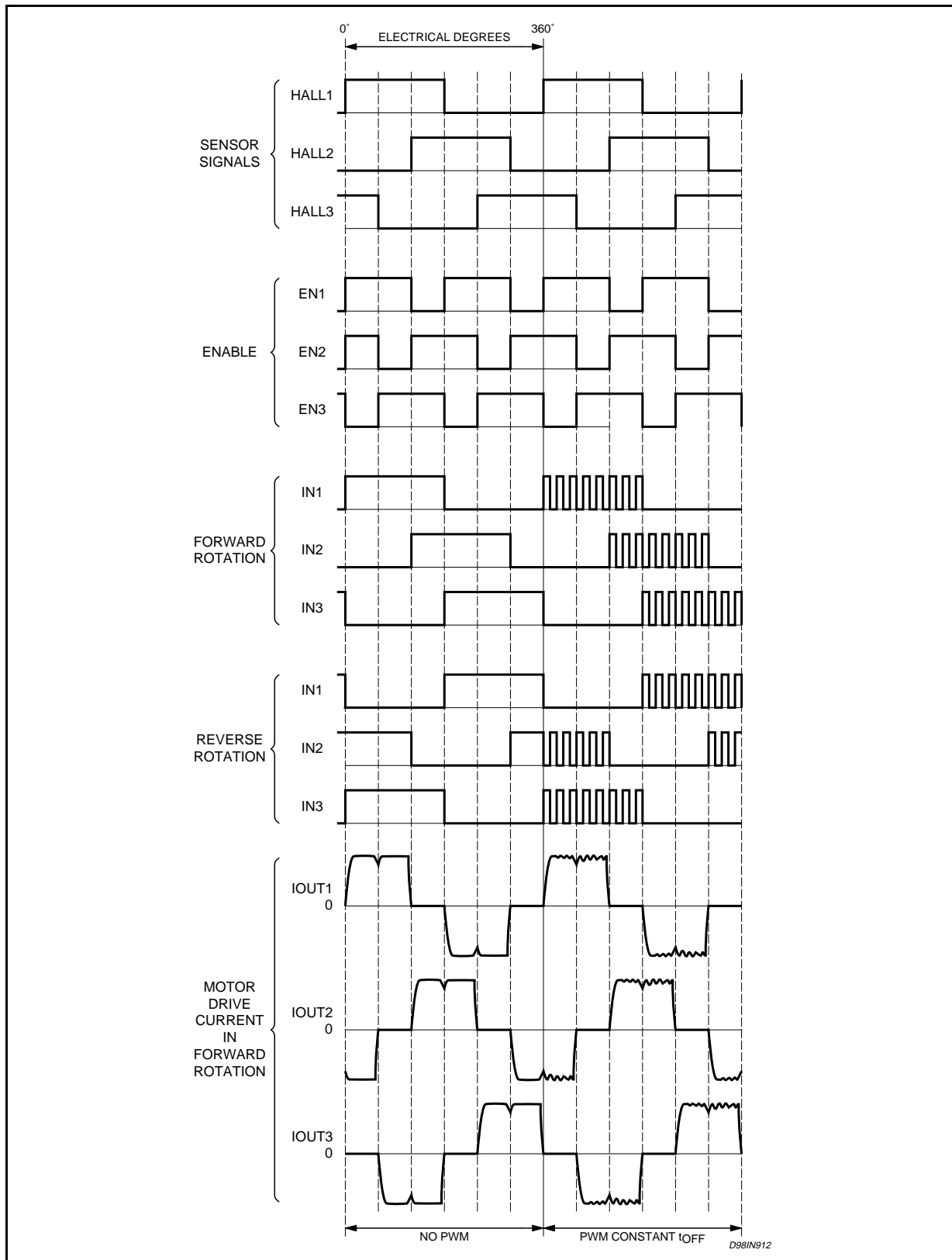








Figure 17.



## AN1088 APPLICATION NOTE

### Layout Considerations.

Special attention must be taken to avoid overvoltages at Vs and additional negative voltages to the SENSE pins and noise due to distributed inductance. Thus the input capacitor must be connected close to the Vs pins with symmetrical paths. The paths between the SENSE pins and the input capacitor ground have to be minimized and symmetrical. The sensing resistors must be non-inductive. The device GND has to be connected with a separate path to the input capacitor ground.

Figure 19. Application Board Layout.

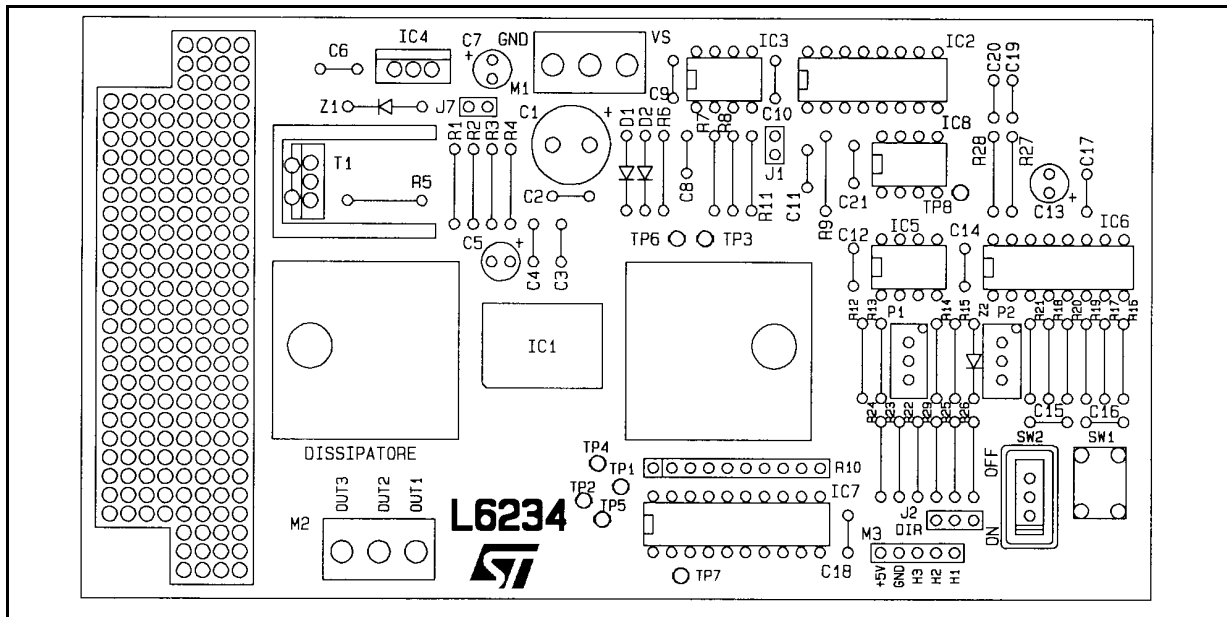


Figure 20. Component side.

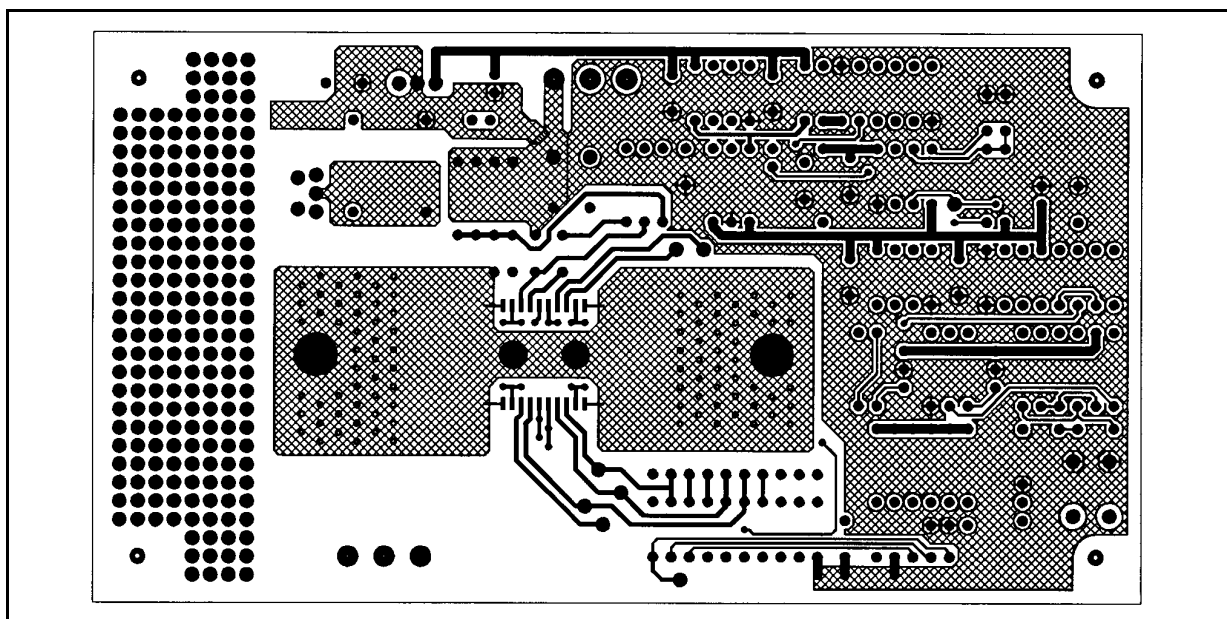
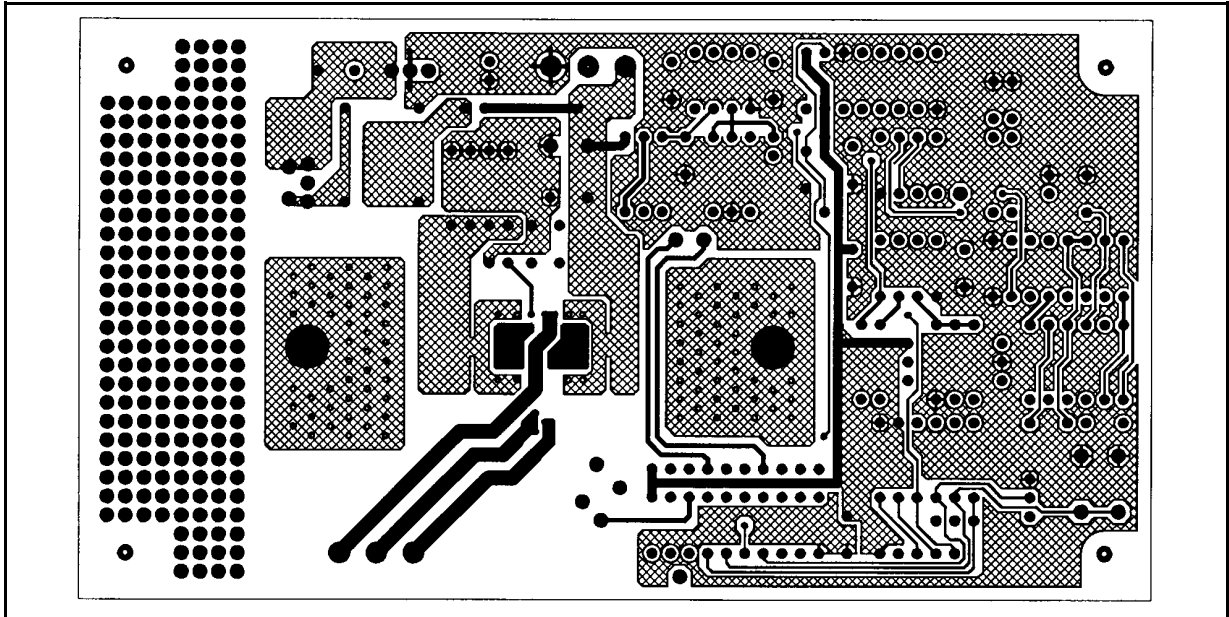


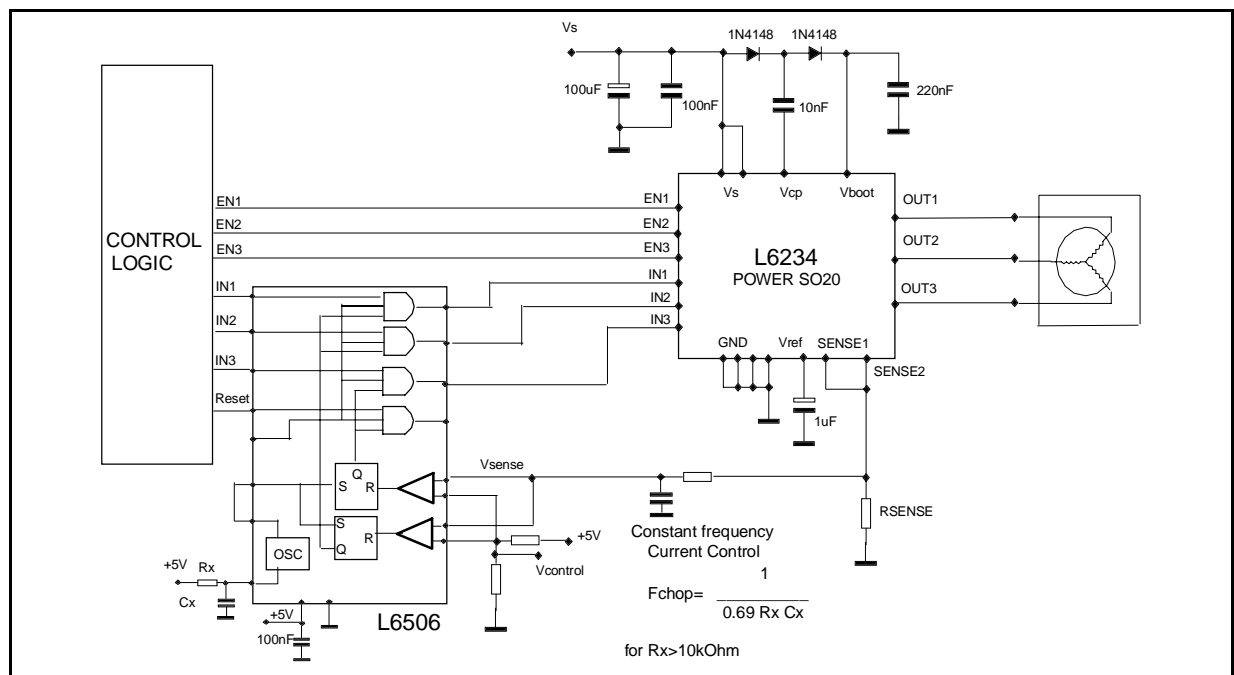
Figure 21. Copper side.

**APPLICATION IDEAS.**

The L6234 can be used in many different applications. Typical examples are a half bridge driver using one channel and a full bridge driver using two channels. In addition, the bridges can be paralleled to reduce the  $R_{DS(on)}$  and the device dissipation.

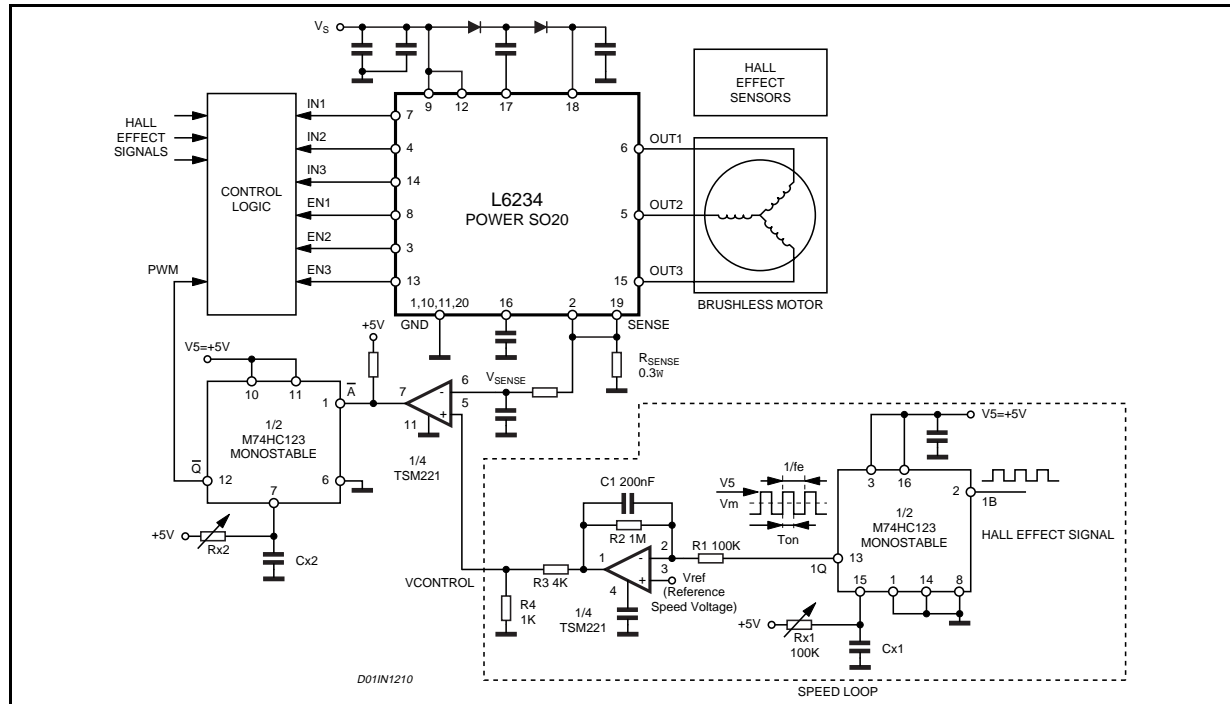
The paralleled configuration can also be used to increase output current capability. Channel 1 can be paralleled with Channel 3 or Channel 2 can be paralleled with Channel 3. Channel 1 should not be paralleled with Channel 2 because the sources of their low side DMOSs are connected to the same SENSE1 pin.

Application ideas for the L6234 follow.

**Figure 22. Constant frequency current control**

## Low Cost Application with Speed and Torque Control Loops.

Figure 23. Complete three phase brushless motor application with speed and torque control.



A low cost solution to obtain a complete three phase brushless motor control application with speed and torque closed control loop is shown in Fig. 23. This simple low cost solution is useful when high dynamic performances and accuracy of the speed loop are not required.

The current regulation limit, which determines the torque, is given by  $V_{control}/R_{sense}$ . The constant toff of the PWM is fixed by  $R_{x2}$  and  $C_{x2}$ .

The speed loop is realised using a Hall effect signal, whose frequency is proportional to the motor speed. At each positive transition of the Hall effect sensors the monostable maintains the pulse for a constant time,  $T_{on}$ , with a fixed amplitude,  $V_5$ . The average value of this signal is proportional to the frequency of the Hall effect signal and the motor speed. An OP-AMP configured as an integrator, filters this signal and compares it with a reference voltage,  $V_{ref}$ , which sets the speed. The generated error signal is the control voltage,  $V_{control}$ , of the current loop. Therefore the current loop modifies the produced torque in order to regulate the speed at the desired value.

The values of  $C_f$  and  $R_2$  should be chosen to obtain a nearly ripple free op-amp output, even at low motor speed. This constrain limits the system bandwidth and so limits the response time of the loop.

The regulated speed, for a rotor with  $n$  pairs of permanent magnetic poles, is given by :

$$\omega_m = \frac{\left(1 + \frac{R_1}{R_2}\right)}{V_5 \cdot T_{on} \cdot n + \frac{1}{KG}} \cdot V_{ref} \cdot 60 \quad [\text{RPM}]$$

$$\text{with } KG = \frac{R_4}{R_3 + R_4} \cdot K_t \cdot \frac{1}{R_{sense}} \cdot \frac{1}{B} \cdot \frac{R_2}{R_1}$$

in which  $K_t$ , expressed in  $[\text{Nm/A}]$ , is the Motor Torque constant and  $B$ , expressed in  $[\text{Nms}]$ , is the Total Viscous Friction.

In most cases  $1/KG$  can be neglected.

The  $T_{on}$  values, given by  $K_C \times 1/R \times 1$ , must be less than the period of the Hall effect electrical signal at the desired motor speed, so  $T_{on}$  must meet the requirement of 1.1 :

$$(1.1) \quad T_{on} < \frac{60}{n \cdot \omega_m}$$

For the motor and the load used in this application, which have the following parameters :

$J_t = 10^{-4} \text{ [Kg} \cdot \text{m}^2 \text{] (Motor plus Load Inertia Moment);}$   $K_t = 10^{-2} \text{ [Nm/A];}$   $B = 10^{-5} \text{ [Nms]}$   
 $n=4$  ;  $R_1=100k \pm 10\% \text{ [k}\Omega \text{] ;}$   $R_2=1M \pm 1\% \text{ [k}\Omega \text{] ;}$   $C_f=220n \text{ [F]}$

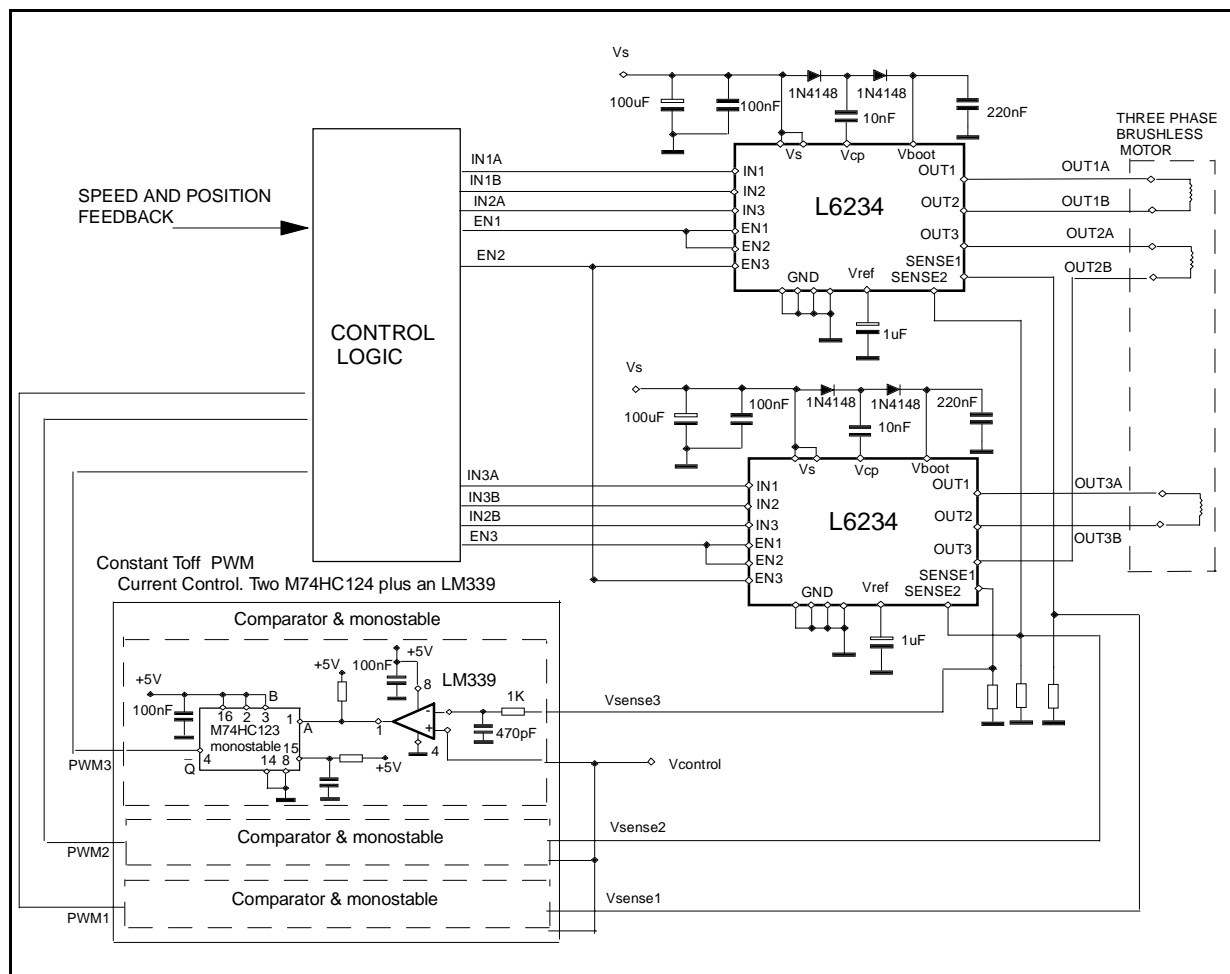
A regulated speed of 6000RPM can be obtained with an accuracy of around  $\pm 3\%$ , considering  $T_{on}$  accuracy of  $\pm 1\%$ , the  $V_5$  and  $V_{ref}$  mismatch of  $\pm 1\%$ .

If the speed is 6000RPM, there are 100 rotor revolution for second, with  $n=4$ , the Hall effect frequency is 400Hz. Therefore  $T_{on}$  has to be lower than 2.5ms (according to equation 1.1).

The phase margin is about  $45^\circ$  and the response time of the speed loop for a speed step variation is around 200ms.

## 6X6 BRUSHLESS APPLICATION

Figure 24. 6x6 Three Phase Brushless Application Circuit



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